Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.300 inches
Terminal Length:
0.980 inches
Overall Diameter:
0.450 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
500.00 amperes collector current, dc preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
88818-a531a256 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0